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REVISION HISTORY

1/13—Rev. F to Rev. G

Changes to Endnote 2, Table 1	3
Changes to Ordering Guide	15

11/12—Rev. E to Rev. F

Added 4-Lead LFCSP_WD	Universal
Changes to Features Section, General Description Section, and Product Highlights Section	1
Added Figure 2; Renumbered Sequentially	1
Added Note 2, Table 1; Renumbered Sequentially	3
Changes to (Unbolded) For 8-Lead SOIC Package, AD590J and AD590K Parameter, Table 1	3
Changes to Note 1, Table 3	5
Changes to Product Description Section	6
Change to Figure 6	6
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Moved Nonlinearity Section	8
Change to Figure 13	8
Changes to General Applications Section	10
Changes to Figure 17 and Figure 19	10

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Changes to Figure 24	12
Updated Outline Dimensions Section	14
Changes to Ordering Guide	14

9/09—Rev. D to Rev. E

Changes to Product Description Section	6
Updated Outline Dimensions	13
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1/06—Rev. C to Rev. D

Updated Format	Universal
Changes to Figure 4 Equation	4

9/03—Rev. B to Rev. C

Added SOIC-8 Package	Universal
Change to Figure 1	1
Updated Outline Dimensions	13
Added Ordering Guide	14

SPECIFICATIONS

AD590J AND AD590K SPECIFICATIONS

25°C and $V_S = 5\text{ V}$, unless otherwise noted.¹

Table 1.

Parameter	AD590J ²			AD590K			Unit
	Min	Typ	Max	Min	Typ	Max	
POWER SUPPLY							
Operating Voltage Range	4		30	4		30	V
OUTPUT							
Nominal Current Output @ 25°C (298.2 K)		298.2			298.2		μA
Nominal Temperature Coefficient		1			1		μA/K
Calibration Error @ 25°C			±5.0			±2.5	°C
Absolute Error (Over Rated Performance Temperature Range)							
Without External Calibration Adjustment			±10			±5.5	°C
With 25°C Calibration Error Set to Zero			±3.0			±2.0	°C
Nonlinearity							
For TO-52 and FLATPACK Packages			±1.5			±0.8	°C
For 8-Lead SOIC Package			±1.5			±1.0	°C
For 4-Lead LFCSP Package			±1.5				°C
Repeatability ³			±0.1			±0.1	°C
Long-Term Drift ⁴			±0.1			±0.1	°C
Current Noise		40			40		pA/√Hz
Power Supply Rejection							
4 V ≤ V_S ≤ 5 V		0.5			0.5		μA/V
5 V ≤ V_S ≤ 15 V		0.2			0.2		μV/V
15 V ≤ V_S ≤ 30 V		0.1			0.1		μA/V
Case Isolation to Either Lead		10 ¹⁰			10 ¹⁰		Ω
Effective Shunt Capacitance		100			100		pF
Electrical Turn-On Time		20			20		μs
Reverse Bias Leakage Current (Reverse Voltage = 10 V) ⁵		10			10		pA

¹ Specifications shown in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels. All minimum and maximum specifications are guaranteed, although only those shown in **boldface** are tested on all production units.

² The LFCSP package has a reduced operating temperature range of -40°C to +125°C.

³ Maximum deviation between +25°C readings after temperature cycling between -55°C and +150°C; guaranteed, not tested.

⁴ Conditions: constant 5 V, constant 125°C; guaranteed, not tested.

⁵ Leakage current doubles every 10°C.

AD590L AND AD590M SPECIFICATIONS

25°C and $V_S = 5\text{ V}$, unless otherwise noted.¹

Table 2.

Parameter	AD590L			AD590M			Unit
	Min	Typ	Max	Min	Typ	Max	
POWER SUPPLY							
Operating Voltage Range	4		30	4		30	V
OUTPUT							
Nominal Current Output @ 25°C (298.2 K)		298.2			298.2		μA
Nominal Temperature Coefficient		1			1		μA/K
Calibration Error @ 25°C			±1.0			±0.5	°C
Absolute Error (Over Rated Performance Temperature Range)							°C
Without External Calibration Adjustment			±3.0			±1.7	°C
With ± 25°C Calibration Error Set to Zero			±1.6			±1.0	°C
Nonlinearity			±0.4			±0.3	°C
Repeatability ²			±0.1			±0.1	°C
Long-Term Drift ³			±0.1			±0.1	°C
Current Noise		40			40		pA/√Hz
Power Supply Rejection							
4 V ≤ V_S ≤ 5 V		0.5			0.5		μA/V
5 V ≤ V_S ≤ 15 V		0.2			0.2		μA/V
15 V ≤ V_S ≤ 30 V		0.1			0.1		μA/V
Case Isolation to Either Lead		10 ¹⁰			10 ¹⁰		Ω
Effective Shunt Capacitance		100			100		pF
Electrical Turn-On Time		20			20		μs
Reverse Bias Leakage Current (Reverse Voltage = 10 V) ⁴		10			10		pA

¹ Specifications shown in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels. All minimum and maximum specifications are guaranteed, although only those shown in **boldface** are tested on all production units.

² Maximum deviation between +25°C readings after temperature cycling between -55°C and +150°C; guaranteed, not tested.

³ Conditions: constant 5 V, constant 125°C; guaranteed, not tested.

⁴ Leakage current doubles every 10°C.

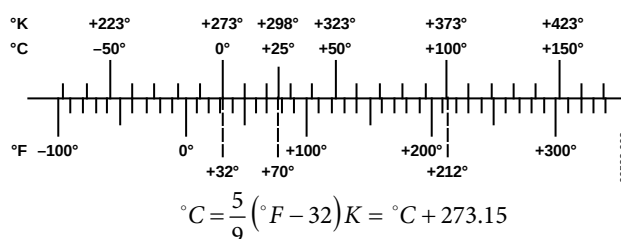


Figure 5. Temperature Scale Conversion Equations

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Forward Voltage (E+ or E–)	44 V
Reverse Voltage (E+ to E–)	–20 V
Breakdown Voltage (Case E+ or E–)	±200 V
Rated Performance Temperature Range ¹	–55°C to +150°C
Storage Temperature Range ¹	–65°C to +155°C
Lead Temperature (Soldering, 10 sec)	300°C

¹ The AD590 was used at –100°C and +200°C for short periods of measurement with no physical damage to the device. However, the absolute errors specified apply to only the rated performance temperature range. Applicable to 2-lead FLATPACK and 3-pin TO-52 packages only.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PRODUCT DESCRIPTION

The AD590 is a 2-terminal temperature-to-voltage transducer. It is available in a variety of accuracy grades and packages. When using the AD590 in die form, the chip substrate must be kept electrically isolated (floating) for correct circuit operation.

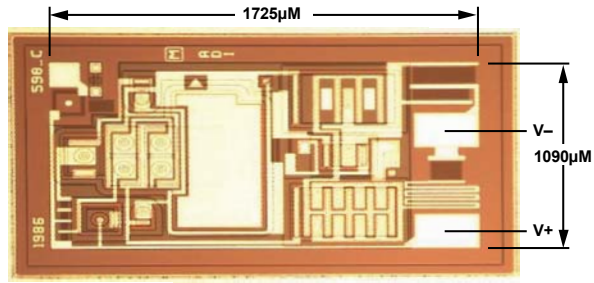


Figure 6. Metallization Diagram

The AD590 uses a fundamental property of the silicon transistors from which it is made to realize its temperature proportional characteristic: if two identical transistors are operated at a constant ratio of collector current densities, r , then the difference in their base-emitter voltage is $(kT/q)(\ln r)$. Because both k (Boltzman's constant) and q (the charge of an electron) are constant, the resulting voltage is directly proportional to absolute temperature (PTAT). (For a more detailed description, see M.P. Timko, "A Two-Terminal IC Temperature Transducer," IEEE J. Solid State Circuits, Vol. SC-11, p. 784-788, Dec. 1976. Understanding the Specifications-AD590.)

In the AD590, this PTAT voltage is converted to a PTAT current by low temperature coefficient thin-film resistors. The total current of the device is then forced to be a multiple of this PTAT current. Figure 7 is the schematic diagram of the AD590. In this figure, Q8 and Q11 are the transistors that produce the PTAT voltage. R5 and R6 convert the voltage to current. Q10, whose collector current tracks the collector currents in Q9 and Q11, supplies all the bias and substrate leakage current for the rest of the circuit, forcing the total current to be PTAT. R5 and R6 are laser-trimmed on the wafer to calibrate the device at 25°C.

Figure 8 shows the typical V-I characteristic of the circuit at 25°C and the temperature extremes.

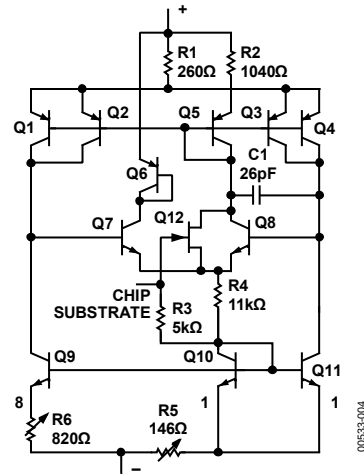


Figure 7. Schematic Diagram

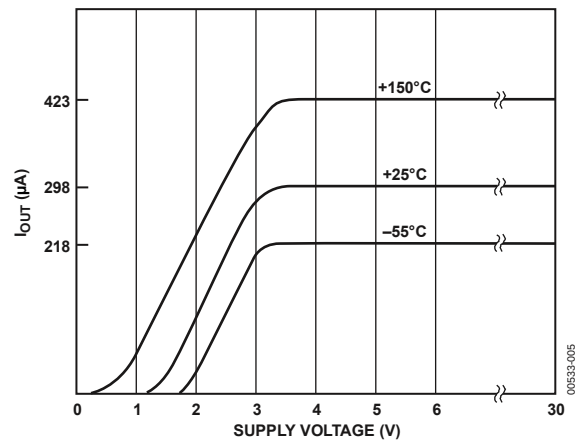


Figure 8. V-I Plot

EXPLANATION OF TEMPERATURE SENSOR SPECIFICATIONS

The way in which the AD590 is specified makes it easy to apply it in a wide variety of applications. It is important to understand the meaning of the various specifications and the effects of the supply voltage and thermal environment on accuracy.

The AD590 is a PTAT current regulator. (Note that $T (^{\circ}\text{C}) = T (\text{K}) - 273.2$. Zero on the Kelvin scale is absolute zero; there is no lower temperature.) That is, the output current is equal to a scale factor times the temperature of the sensor in degrees Kelvin. This scale factor is trimmed to $1 \mu\text{A}/\text{K}$ at the factory, by adjusting the indicated temperature (that is, the output current) to agree with the actual temperature. This is done with 5 V across the device at a temperature within a few degrees of 25°C (298.2 K). The device is then packaged and tested for accuracy over temperature.

CALIBRATION ERROR

At final factory test, the difference between the indicated temperature and the actual temperature is called the calibration error. Since this is a scale factory error, its contribution to the total error of the device is PTAT. For example, the effect of the 1°C specified maximum error of the AD590L varies from 0.73°C at -55°C to 1.42°C at 150°C . Figure 9 shows how an exaggerated calibration error would vary from the ideal over temperature.

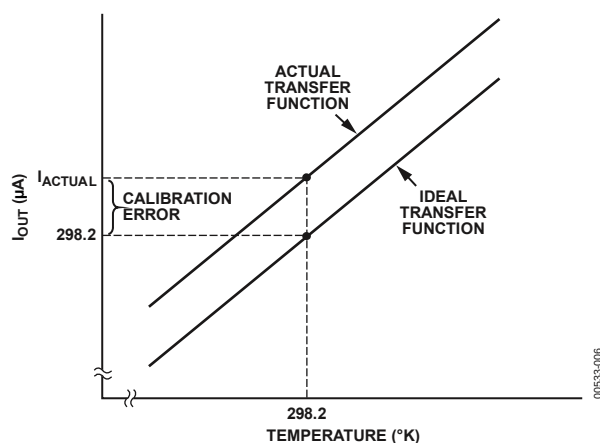


Figure 9. Calibration Error vs. Temperature

The calibration error is a primary contributor to the maximum total error in all AD590 grades. However, because it is a scale factor error, it is particularly easy to trim. Figure 10 shows the most elementary way of accomplishing this.

To trim this circuit, the temperature of the AD590 is measured by a reference temperature sensor and R is trimmed so that $V_T = 1 \text{ mV}/\text{K}$ at that temperature. Note that when this error is trimmed out at one temperature, its effect is zero over the entire

temperature range. In most applications, there is a current-to-voltage conversion resistor (or, as with a current input ADC, a reference) that can be trimmed for scale factor adjustment.

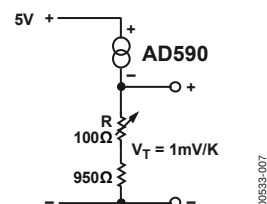


Figure 10. One Temperature Trim

ERROR VS. TEMPERATURE: CALIBRATION ERROR TRIMMED OUT

Each AD590 is tested for error over the temperature range with the calibration error trimmed out. This specification could also be called the variance from PTAT, because it is the maximum difference between the actual current over temperature and a PTAT multiplication of the actual current at 25°C . This error consists of a slope error and some curvature, mostly at the temperature extremes. Figure 11 shows a typical AD590K temperature curve before and after calibration error trimming.

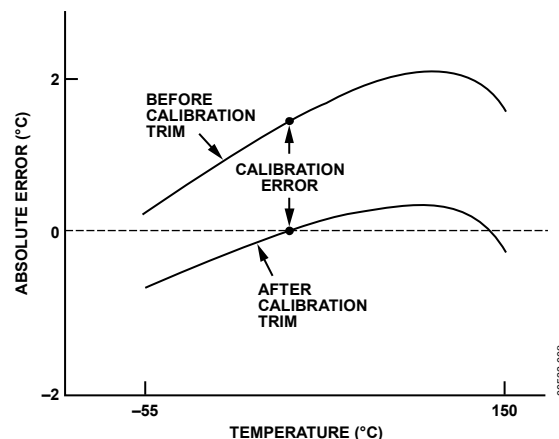


Figure 11. Effect to Scale Factor Trim on Accuracy

ERROR VS. TEMPERATURE: NO USER TRIMS

Using the AD590 by simply measuring the current, the total error is the variance from PTAT, described above, plus the effect of the calibration error over temperature. For example, the AD590L maximum total error varies from 2.33°C at -55°C to 3.02°C at 150°C . For simplicity, only the large figure is shown on the specification page.

NONLINEARITY

Nonlinearity as it applies to the AD590 is the maximum deviation of current over temperature from a best-fit straight line. The nonlinearity of the AD590 over the -55°C to $+150^{\circ}\text{C}$ range is superior to all conventional electrical temperature sensors such as thermocouples, RTDs, and thermistors. Figure 12 shows the nonlinearity of the typical AD590K from Figure 11.

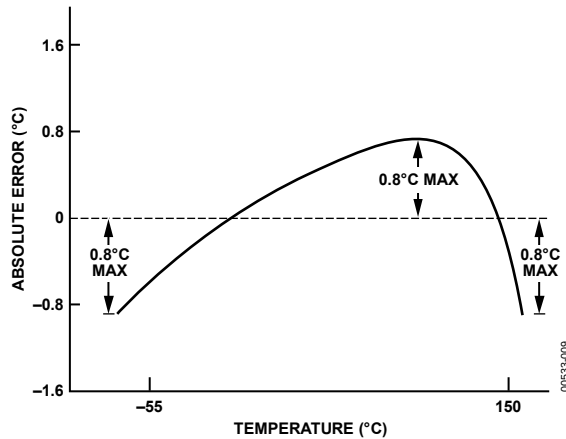


Figure 12. Nonlinearity

Figure 13 shows a circuit in which the nonlinearity is the major contributor to error over temperature. The circuit is trimmed by adjusting R1 for a 0 V output with the AD590 at 0°C . R2 is then adjusted for 10 V output with the sensor at 100°C . Other pairs of temperatures can be used with this procedure as long as they are measured accurately by a reference sensor. Note that for 15 V output (150°C), the $V+$ of the op amp must be greater than 17 V. Also, note that $V-$ should be at least -4 V ; if $V-$ is ground, there is no voltage applied across the device.

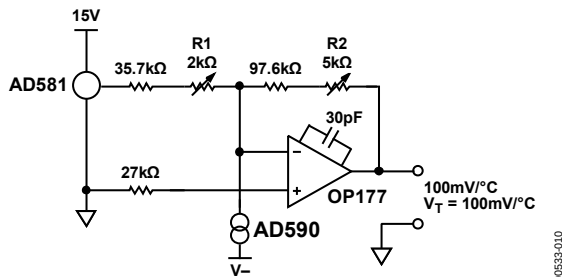


Figure 13. 2-Temperature Trim

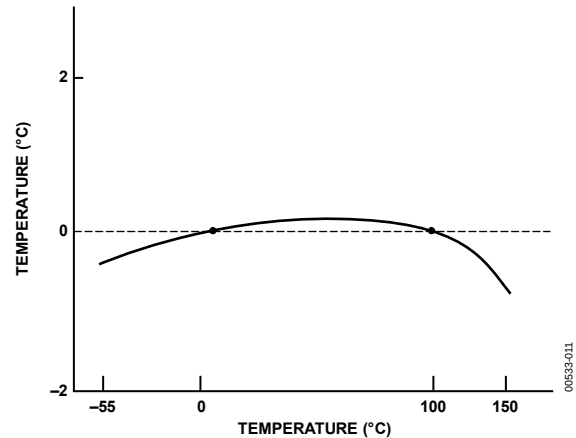


Figure 14. Typical 2-Trim Accuracy

VOLTAGE AND THERMAL ENVIRONMENT EFFECTS

The power supply rejection specifications show the maximum expected change in output current vs. input voltage changes. The insensitivity of the output to input voltage allows the use of unregulated supplies. It also means that hundreds of ohms of resistance (such as a CMOS multiplexer) can be tolerated in series with the device.

It is important to note that using a supply voltage other than 5 V does not change the PTAT nature of the AD590. In other words, this change is equivalent to a calibration error and can be removed by the scale factor trim (see Figure 11).

The AD590 specifications are guaranteed for use in a low thermal resistance environment with 5 V across the sensor. Large changes in the thermal resistance of the sensor's environment change the amount of self-heating and result in changes in the output, which are predictable but not necessarily desirable.

The thermal environment in which the AD590 is used determines two important characteristics: the effect of self-heating and the response of the sensor with time. Figure 15 is a model of the AD590 that demonstrates these characteristics.

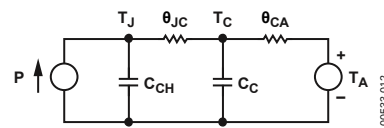


Figure 15. Thermal Circuit Model

As an example, for the TO-52 package, θ_{JC} is the thermal resistance between the chip and the case, about 26°C/W. θ_{CA} is the thermal resistance between the case and the surroundings and is determined by the characteristics of the thermal connection. Power source P represents the power dissipated on the chip. The rise of the junction temperature, T_J , above the ambient temperature, T_A , is

$$T_J - T_A = P(\theta_{JC} + \theta_{CA}) \quad (1)$$

Table 4 gives the sum of θ_{JC} and θ_{CA} for several common thermal media for both the H and F packages. The heat sink used was a common clip-on. Using Equation 1, the temperature rise of an AD590 H package in a stirred bath at 25°C, when driven with a 5 V supply, is 0.06°C. However, for the same conditions in still air, the temperature rise is 0.72°C. For a given supply voltage, the temperature rise varies with the current and is PTAT. Therefore, if an application circuit is trimmed with the sensor in the same thermal environment in which it is used, the scale factor trim compensates for this effect over the entire temperature range.

Table 4. Thermal Resistance

Medium	$\theta_{JC} + \theta_{CA}$ (°C/Watt)		τ (sec) ¹	
	H	F	H	F
Aluminum Block	30	10	0.6	0.1
Stirred Oil ²	42	60	1.4	0.6
Moving Air ³				
With Heat Sink	45	–	5.0	–
Without Heat Sink	115	190	13.5	10.0
Still Air				
With Heat Sink	191	–	108	–
Without Heat Sink	480	650	60	30

¹ τ is dependent upon velocity of oil; average of several velocities listed above.

² Air velocity @ 9 ft/sec.

³ The time constant is defined as the time required to reach 63.2% of an instantaneous temperature change.

The time response of the AD590 to a step change in temperature is determined by the thermal resistances and the thermal capacities of the chip, C_{CH} , and the case, C_C . C_{CH} is about 0.04 Ws/°C for the AD590. C_C varies with the measured medium, because it includes anything that is in direct thermal contact with the case. The single time constant exponential curve of Figure 16 is usually sufficient to describe the time response, $T(t)$. Table 4 shows the effective time constant, τ , for several media.

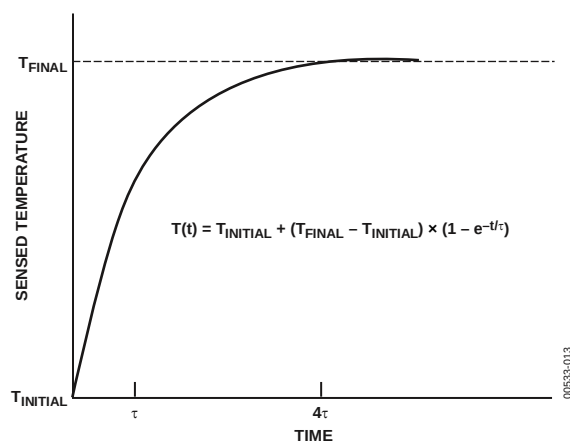
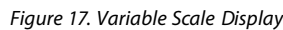
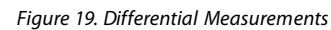


Figure 16. Time Response Curve

Figure 17 shows a typical use of the AD590 in a remote temperature sensing application. The AD590 is used as a thermometer circuit that measures temperature from -55°C to $+150^{\circ}\text{C}$, with an output voltage of $1\text{ mV}/^{\circ}\text{K}$. Because the AD590 measures absolute temperature (its nominal output is 1 mA/K), the output must be offset by 273.2 mA to read out in degrees Celsius.



The circuit in Figure 19 demonstrates one method by which differential temperature measurements can be made. R1 and R2 can be used to trim the output of the op amp to indicate a desired temperature difference. For example, the inherent offset between the two devices can be trimmed in. If V_+ and V_- are radically different, then the difference in internal dissipation causes a differential internal temperature rise. This effect can be used to measure the ambient thermal resistance seen by the sensors in applications such as fluid-level detectors or anemometry.



The diagram shows a Wheatstone bridge circuit for temperature measurement. The bridge is powered by a 7.5V source. The bridge arms consist of an AD580 (labeled V_{OUT}), a 52.3Ω resistor, an 8.66kΩ resistor, and a thermistor R_T (1kΩ). The AD580 is connected to the 7.5V source and the 52.3Ω resistor. The AD590 is connected to the 52.3Ω resistor and the 8.66kΩ resistor. The output of the bridge is connected to a meter. The thermistor R_T is connected to the 8.66kΩ resistor and the meter. The meter is also connected to the 52.3Ω resistor. The thermistor R_T is connected to the 8.66kΩ resistor and the meter. The meter is also connected to the 52.3Ω resistor. The thermistor R_T is connected to the 8.66kΩ resistor and the meter. The meter is also connected to the 52.3Ω resistor.

Figure 20. Cold Junction Compensation Circuit for Type J Thermocouple

Figure 21 is an example of a current transmitter designed to be used with 40 V, 1 k Ω systems; it uses its full current range of 4 to 20 mA for a narrow span of measured temperatures. In this example, the 1 μ A/K output of the AD590 is amplified to 1 mA/ $^{\circ}$ C and offset so that 4 mA is equivalent to 17 $^{\circ}$ C and 20 mA is equivalent to 33 $^{\circ}$ C. R_T is trimmed for proper reading at an intermediate reference temperature. With a suitable choice of resistors, any temperature range within the operating limits of the AD590 can be chosen.

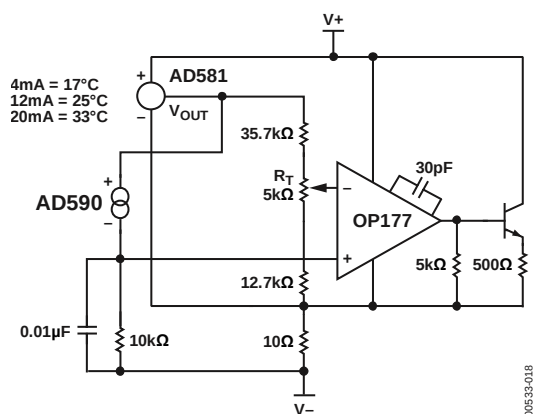


Figure 21. 4 to 20 mA Current Transmitter

Figure 22 is an example of a variable temperature control circuit (thermostat) using the AD590. R_H and R_L are selected to set the high and low limits for R_{SET} . R_{SET} could be a simple pot, a calibrated multiturn pot, or a switched resistive divider. Powering the AD590 from the 10 V reference isolates the AD590 from supply variations while maintaining a reasonable voltage (~ 7 V) across it. Capacitor C1 is often needed to filter extraneous noise from remote sensors. R_B is determined by the β of the power transistor and the current requirements of the load.

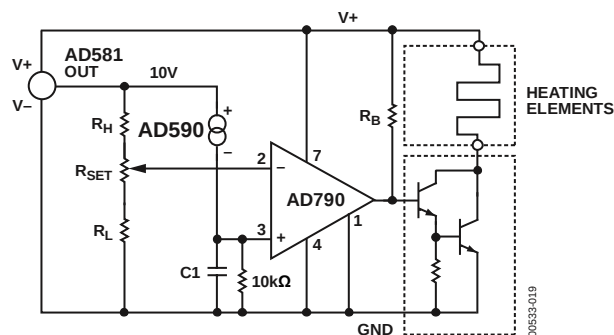


Figure 22. Simple Temperature Control Circuit

The voltage compliance and the reverse blocking characteristic of the AD590 allow it to be powered directly from 5 V CMOS logic. This permits easy multiplexing, switching, or pulsing for minimum internal heat dissipation. In Figure 23, any AD590 connected to a logic high passes a signal current through the current measuring circuitry, while those connected to a logic zero pass insignificant current. The outputs used to drive the AD590s can be employed for other purposes, but the additional capacitance due to the AD590 should be taken into account.

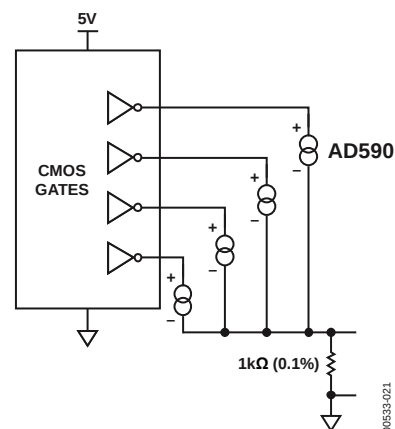


Figure 23. AD590 Driven from CMOS Logic

Figure 24 demonstrates a method of multiplexing the AD590 in the 2-trim mode (see Figure 13 and Figure 14). Additional AD590s and their associated resistors can be added to multiplex up to eight channels of $\pm 0.5^\circ\text{C}$ absolute accuracy over the

temperature range of -55°C to $+125^\circ\text{C}$. The high temperature restriction of 125°C is due to the output range of the op amps; output to 150°C can be achieved by using a 20 V supply for the op amp.

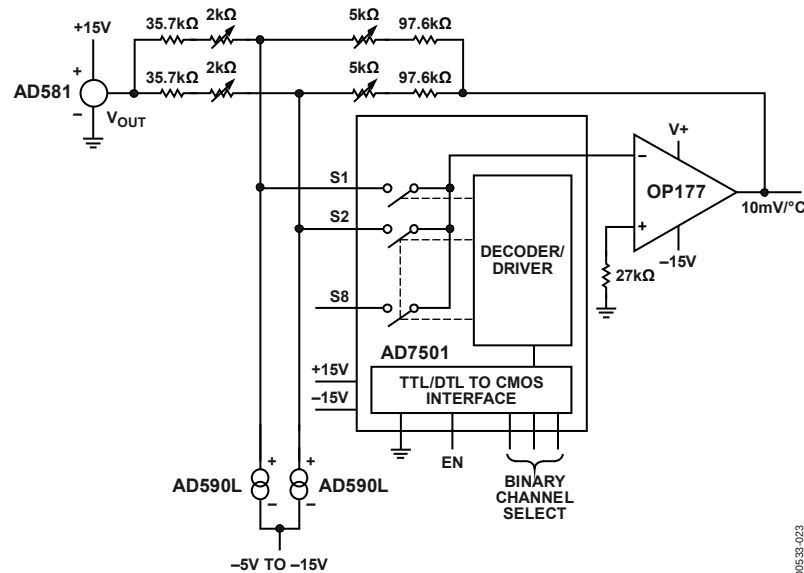


Figure 24. 8-Channel Multiplexer

00533-023

OUTLINE DIMENSIONS

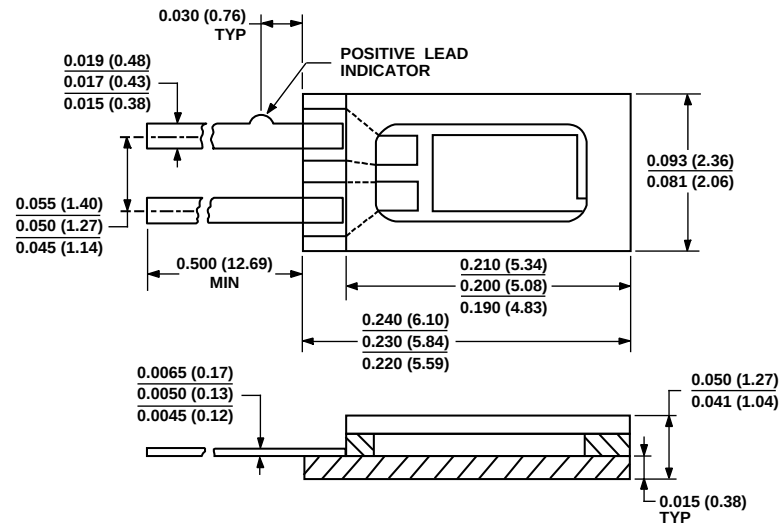
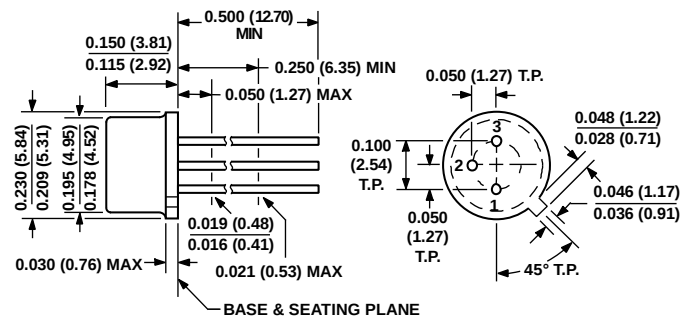


Figure 25. 2-Lead Ceramic Flat Package [FLATPACK]
(F-2)

Dimensions shown in inches and (millimeters)

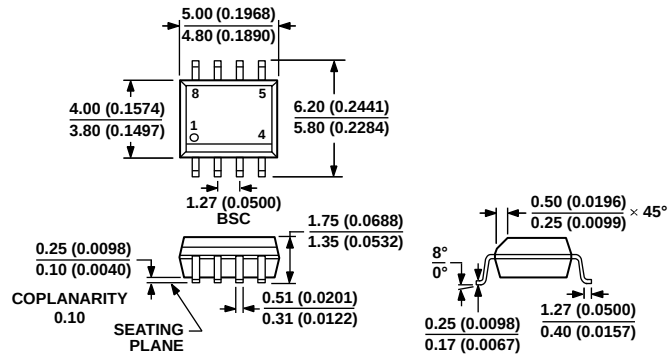


CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 26. 3-Pin Metal Header Package [TO-52]
(H-03-1)

Dimensions shown in inches and (millimeters)

022306-A

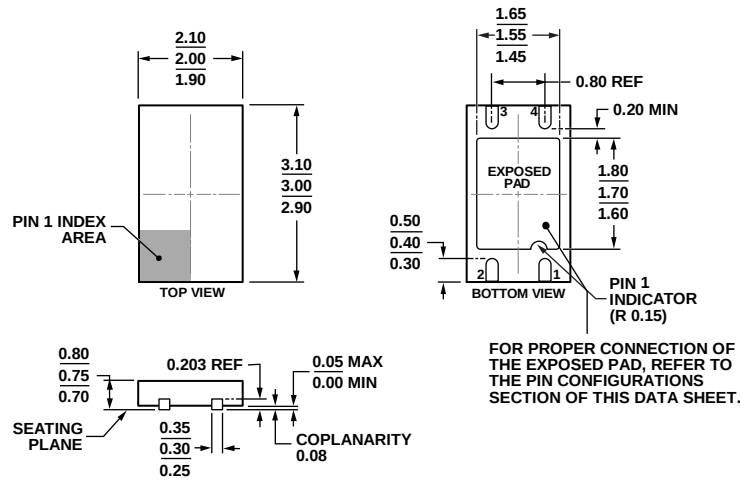


COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 27. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-8)

Dimensions shown in millimeters and (inches)

012407-A



COMPLIANT TO JEDEC STANDARDS MO-229

Figure 28. 4-Lead Lead Frame Chip Scale Package [LF CSP_WD]
2.00 mm × 3.00 mm Body, Very Very Thin, Dual Lead
(CP-4-1)

Dimensions shown in millimeters

09-07-2010-B

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Package Option	Branding
AD590JF	–55°C to +150°C	2-Lead FLATPACK	F-2	
AD590JH	–55°C to +150°C	3-Pin TO-52	H-03-1	
AD590JR	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590JRZ	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590KF	–55°C to +150°C	2-Lead FLATPACK	F-2	
AD590KH	–55°C to +150°C	3-Pin TO-52	H-03-1	
AD590KR	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590KR-REEL	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590KRZ	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590KRZ-RL	–55°C to +150°C	8-Lead SOIC_N	R-8	
AD590LF	–55°C to +150°C	2-Lead FLATPACK	F-2	
AD590LH	–55°C to +150°C	3-Pin TO-52	H-03-1	
AD590MF	–55°C to +150°C	2-Lead FLATPACK	F-2	
AD590MH	–55°C to +150°C	3-Pin TO-52	H-03-1	
AD590JCHIPS	–55°C to +150°C	Bare Die	H-03-1	
AD590JCPZ-R5	–40°C to +125°C	4-Lead LFCSP_WD	CP-4-1	7A
AD590JCPZ-RL7	–40°C to +125°C	4-Lead LFCSP_WD	CP-4-1	7A

¹ Z = RoHS Compliant Part.

² The AD590xF models and the AD590xH models are available in 883B.

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